

UTC UNISONIC TECHNOLOGIES CO., LTD

6N10Z

Power MOSFET

6.5 Amps, 100 Volts N-CHANNEL POWER MOSFET

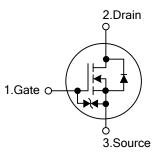
DESCRIPTION

The UTC 6N10Z is an N-Channel enhancement mode power FET providing customers with excellent switching performance and minimum on-state resistance.

The UTC 6N10Z is generally applied in voltage applications, such as DC motor control, audio amplifier and high efficiency switching DC/DC converters.

FEATURES

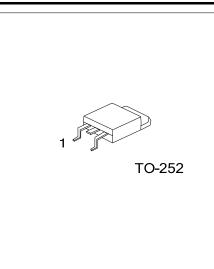
- * 6.5A, 100V, R_{DS(ON)} = 0.2Ω @V_{GS} = 10 V
- * Fast switching
- * Improved dv/dt capability
- **SYMBOL**



ORDERING INFORMATION

Ordering Number		Daakaga	Pin Assignment			Docking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
6N10ZL-TN3-R	6N10ZG-TN3-R	TO-252	G	D	S	Tape Reel	
Note: Pin Assignment: G: Gate D: Drain S: Source							

6N10ZL-TN3-T (1)Packing Type (1) T: Tube, R: Tape Reel (2)Package Type (2) TN3: TO-252 (3)Lead Free (3) L: Lead Free, G: Halogen Free Gwww.flying1688.com



■ ABSOLUTE MAXIMUM RATINGS (T_c =25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DS}	100	V
Gate-Source Voltage		V _{GS}	±20	V
	Continuous	I _D	6.5	А
Continuous Drain Current	Pulsed	I _{DM}	8.0	А
Repetitive Avalanche Energy (Duty Cycle ≤1%)	L=0.1mH	E _{AR}	1.25	mJ
Power Dissipation		PD	16	W
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55~+150	°C

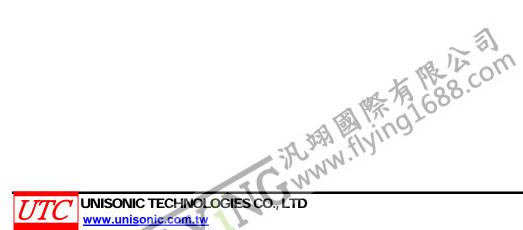
Note : Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ _{JA}	100	°C/W	
Junction to Case	θ _{JC}	7.5	°C/W	

Notes: θ_{JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.

 θ_{JC} is guaranteed by design while θ_{JA} is determined by the user's board deign.



■ ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise noted)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage		BV _{DSS}	I _D =250μA, V _{GS} =0V	100			V	
Drain-Source Leakage Current		I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μA	
			V _{DS} =100V, V _{GS} =0V, T _J =125°C			50	μA	
			V _{DS} =100V, V _{GS} =0V, T _J =150°C			250	μA	
Gate- Source Leakage Current	Forward	1	V _{GS} =+20V, V _{DS} =0V			+10	μA	
	Reverse	I _{GSS}	V _{GS} =-20V, V _{DS} =0V			-10	μA	
On-State Drain Current (Note 2)		I _{D(on)}	V _{DS} =5V, V _{GS} =10V	8.0			Α	
ON CHARACTERISTICS					_			
Gate Threshold Voltage		V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250µA	1.0		3.0	V	
			V _{GS} =10V, I _D =3A		0.125	0.200		
Static Drain-Source On-State Re	sistance	Б	Vgs=10V, Id=3A, TJ=125°C			0.350	Ω	
(Note 2)		R _{DS(ON)}	Vgs=10V, Id=3A, TJ=150°C			0.450	Ω	
			V _{GS} =4.5V, I _D =1.0A		0.140	0.225		
Forward Transconductance (Note 2)		g fs	V _{DS} =15V, I _D =3A		8.5		S	
DYNAMIC PARAMETERS (Note	1)			_				
Input Capacitance		CISS			320		pF	
Output Capacitance		Coss	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		80		pF	
Reverse Transfer Capacitance		C _{RSS}			17		pF	
SWITCHING PARAMETERS				_				
Total Gate Charge (Note 3)		Q_{G}			27	75	nC	
Gate to Source Charge (Note 3)		Q_{GS}	V _{DS} =50V, V _{GS} =5V, I _D =6.5A		2.4		nC	
Gate to Drain Charge (Note 3)		Q_{GD}			6.8		nC	
Turn-ON Delay Time (Note3)		t _{D(ON)}			20	50	ns	
Rise Time (Note 3)		t _R	V _{DD} =50V, R _L =7.5Ω, I _D ≈6.5A,		30	60	ns	
Turn-OFF Delay Time (Note 3)		$t_{D(OFF)}$	V_{GEN} =10V, R_{G} =2.5 Ω		135	165	ns	
Fall-Time (Note 3)		t⊨			60	90	ns	
SOURCE- DRAIN DIODE RATIN	IGS AND CH	ARACTERIS	TICS (T _C =25°C)	_				
Maximum Pulsed Drain-Source Diode		I _{SM}				8.0	А	
Forward Current						0.0	~	
Drain-Source Diode Forward Voltage (Note 2)		V_{SD}	I _F =6.5A, V _{GS} =0V		0.9	1.3	V	
Reverse Recovery Time		t _{RR}	I _F =6.5A, di/dt=100A/μs		35	60	ns	

Notes: 1. Guaranteed by design, not subject to production testing.

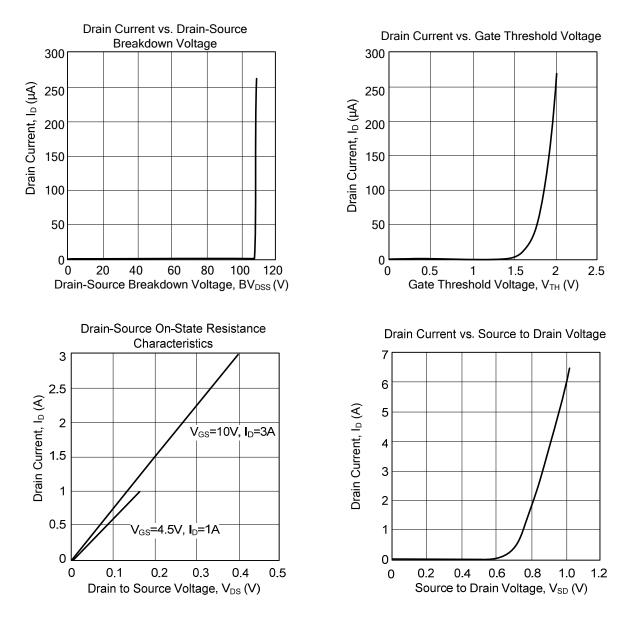
Pulse test; pulse width ≤300 ≤µs, duty cycle ≤2%.

3. Independent of operating temperature.



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TYPICAL CHARACTERISTICS



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